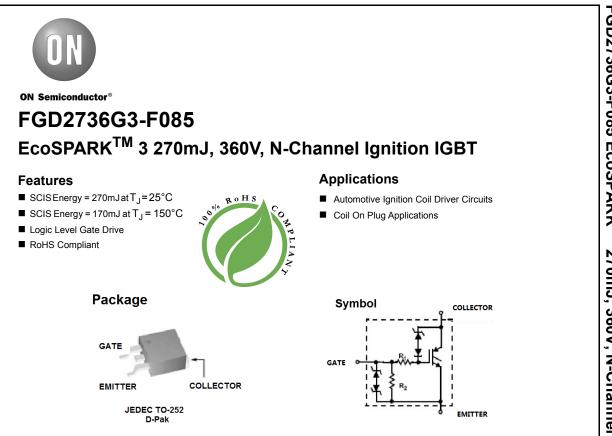
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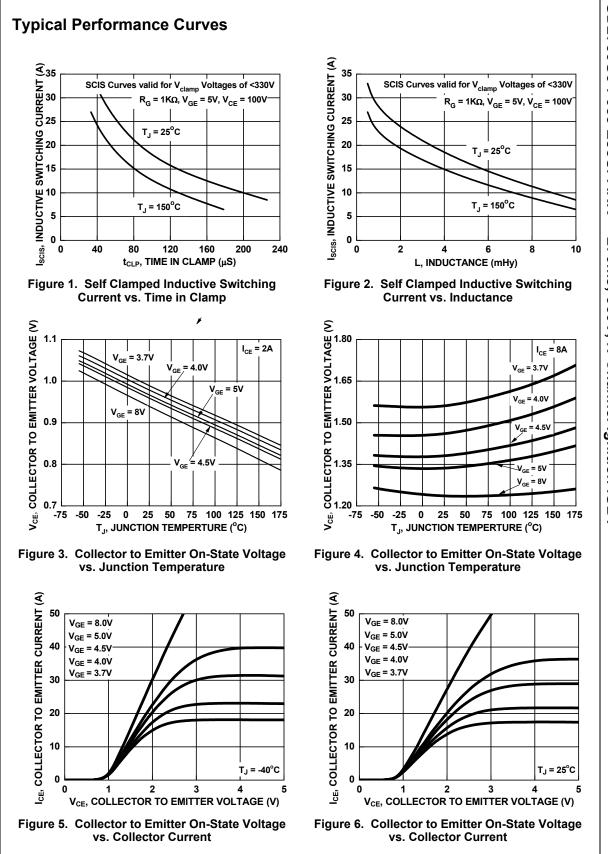
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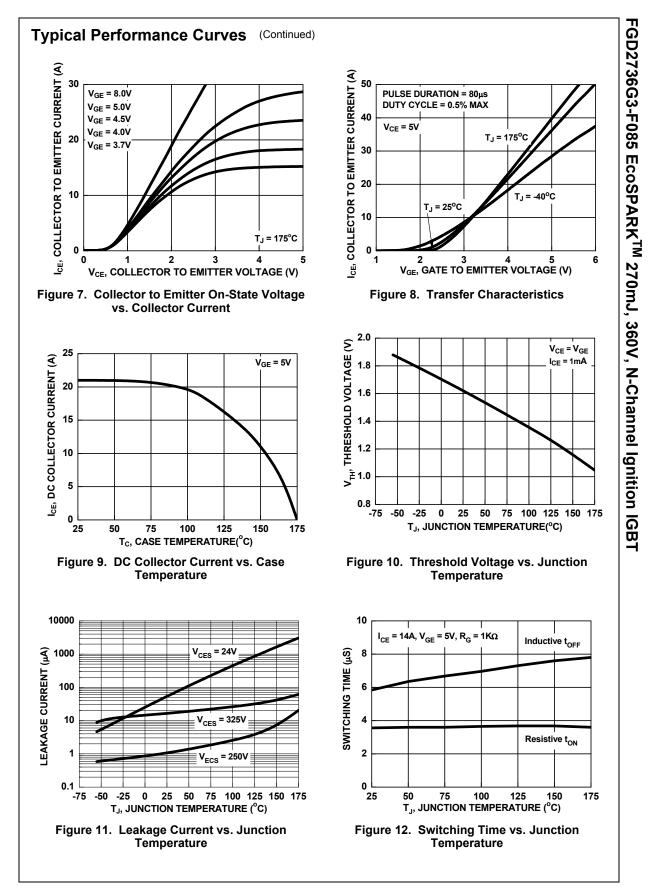


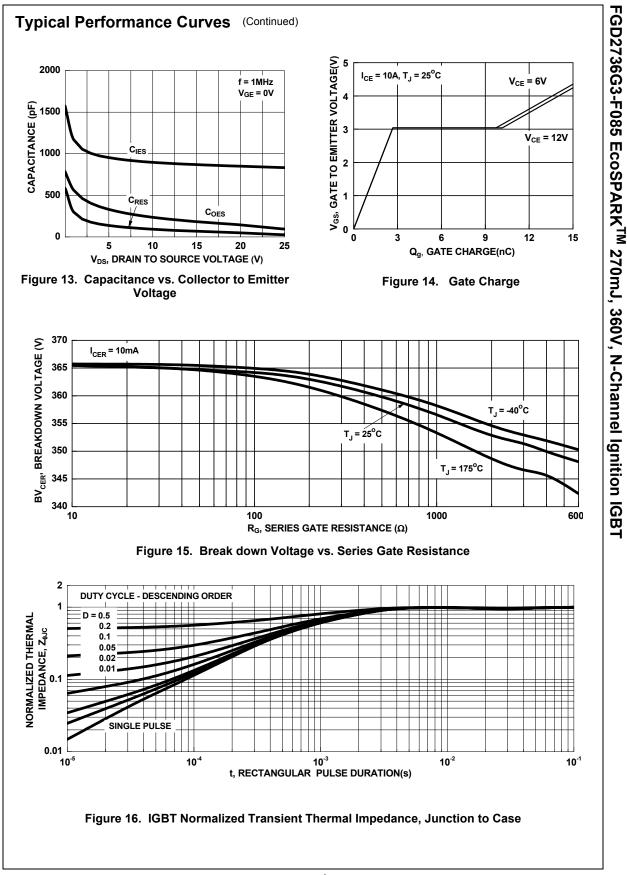
Absolute Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
BV _{CER}	Collector to Emitter Breakdown Voltage (I _C = 1mA)	360	V	
BV _{ECS}	Emitter to Collector Voltage - Reverse Battery Condition (I _C :	28	V	
E _{SCIS25}	I _{SCIS} = 13.4A, L = 3.0mHy, R _{GE} = 1KΩ	T _C = 25°C	270	mJ
E _{SCIS150}	I _{SCIS} = 10.8A, L = 3.0mHy, R _{GE} = 1KΩ	T _C = 150°C	170	mJ
I _{C25}	Collector Current Continuous, at $T_C = 25^{\circ}C$, $V_{GE} = 5.0V$	21	Α	
I _{C110}	Collector Current Continuous, at T _C = 110°C, V _{GE} = 5.0V	18	Α	
V _{GEM}	Gate to Emitter Voltage Continuous		±10	V
P _D	Power Dissipation Total	T _C = 25°C	150	W
	Power Dissipation Derating	T _C > 25°C	1	W/ºC
TJ	Operating Junction Temperature Range	-40 to +175	°C	
T _{STG}	Storage Junction Temperature Range	-40 to +175	°C	
ΤL	Max. Lead Temp. for Soldering (Leads at 1.6mm from case	300	°C	
T _{PKG}	Max Lead Temp for soldering (Package Body for 10s)	260	°C	
ESD	Electrostatic Discharge Voltage at 100pF, 1500 Ω	4	kV	

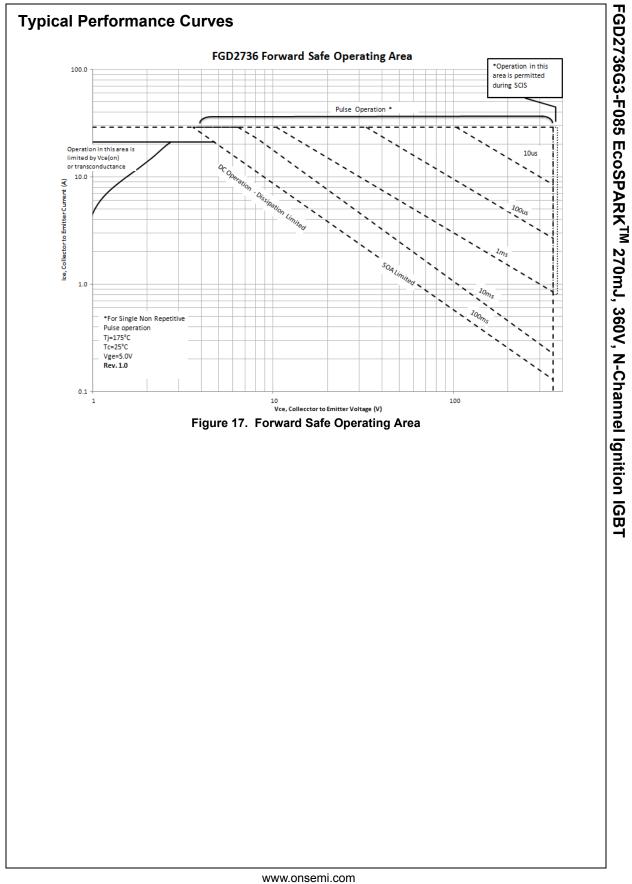
κ _θ JC	DJC Thermal Resistance Junction to Case								1		°C/W	
Electr	ical Ch	aracteristics of	f the	IGBT	T _A = 25°C unles	s othe	erwise note	d				
Symbol		Parameter			Test Condit	ions		Min	Тур	Мах	Units	
Off Cha	aracteris	tics										
BV _{CER}	Collector t	o Emitter Breakdown Vo	oltage	$V_{GE} = 0V, I_{CE} = 2mA,$ $R_{GE} = 1K\Omega,$ $T_{J} = -40 \text{ to } 150^{\circ}\text{C}$			330	-	390	v		
BV _{CES}	Collector to	o Emitter Breakdown Vo	oltage	V _{GE} = 0V, I _{CE} = 10mA,				350	-	410	v	
BV _{ECS}	Emitter to	Collector Breakdown Vo		V _{GE} = 0V, I _{CE} = -75mA, T _J = 25°C				28	-	-	V	
BV _{GES}	Gate to Er	nitter Breakdown Voltag		I _{GES} = ±5mA				±11	±14	-	V	
	Collector t	o Emitter Leakage Curr			0V, R _{GE} = 1KΩ		25°C	-	-	25	μA	
ICER	Collector to Emitter Leakage Current		ent				150°C	-	-	1	mA	
	Emitter to	Collector Leakage Curr	ent	V _{EC} =24V		-	25°C	-	-	1	mA	
IECS			Sinc			T _J =	150°C	-	-	40		
R ₁		te Resistance						-	110	-	Ω	
R ₂	Gate to Er	nitter Resistance						10K	-	30K	Ω	
V _{CE(SAT)}		o Emitter Saturation Vo		V _{GE} = 4V,	I _{CE} = 6A		25°C	-	1.25	1.35	V	
V _{CE(SAT)}	Collector t	o Emitter Saturation Vol	ltage	V _{GE} = 4.5V, I _{CE} = 10A			25°C	-	1.45	1.65	V	
V _{CE(SAT)}	Collector to Emitter Saturation Voltage		ltage			T _J =	150°C		1.6	1.8	V	
Dynam	ic Chara	cteristics										
Q _{G(ON)}	Gate Char	ge	,	V _{GE} = 5V,	V_{CE} = 12V, I_{CE}	= 10A		-	18	-	nC	
	Coto to Er	mitter Threehold Voltage		$I_{CE} = 1mA, V_{CE} = V_{GE},$ $T_J = 25^{\circ}C$ $T_J = 150^{\circ}C$		25°C	1.3	1.6	2.2	v		
V _{GE(TH)}	Gate to Er	nitter Threshold Voltage	e			150 ^o C	0.75	1.1	1.8			
V _{GEP}	Gate to Emitter Plateau Voltage		'	V _{CE} = 12V, I _{CE} = 10A			-	3.0	-	V		
Switch	ing Char	acteristics										
t _{d(ON)R}	Current Tu	ırn-On Delay Time-Resi	istive	Vor = 14\	/ R. = 10			- 1	0.9	4	μS	
t _{rR}	Current Rise Time-Resistive		$V_{GE} = 5V, R_G = 1K\Omega$			-	3	7	μS			
t _{d(OFF)L}	Current Turn-Off Delay Time-Inductive			$V_{CE} = 300V, L = 2mH,$ $V_{GE} = 5V, R_G = 1K\Omega$			-	4.4	15	μS		
t _{fL}	Current Fa	Current Fall Time-Inductive					-	1.9	15	μS		
Order	ing Info	ormation										
Deries	Device Marking Device Page		Pac	ckage Reel Size Ta		Tape V	e Width		Quantity			
Device	2736G3	FGD2736G3-F085	TO-2	252AA	330mm		16mm		2500u			

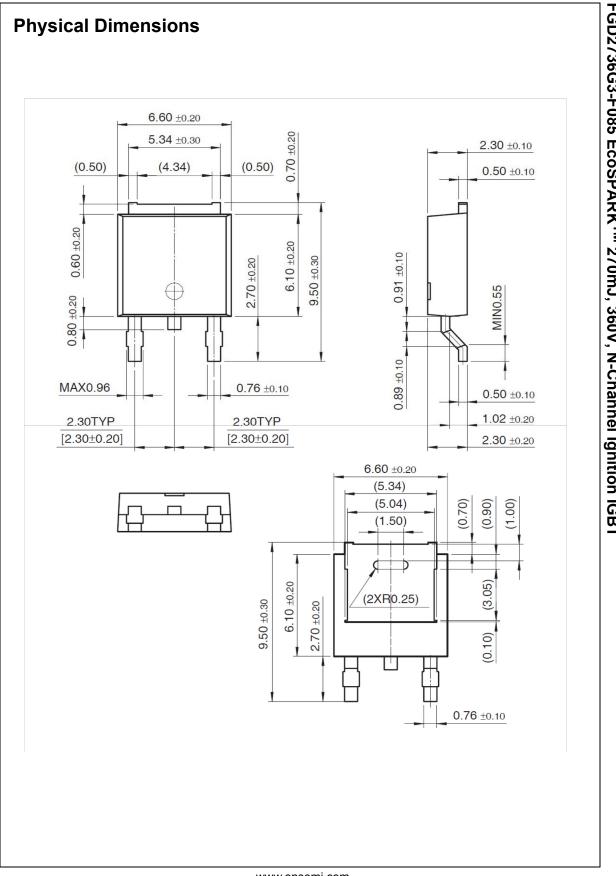






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FGD2736G3-F085 EcoSPARKTM 270mJ, 360V, N-Channel Ignition IGBT

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